# Single Schmitt-Trigger Inverter

The MC74VHC1G14 is a single gate CMOS Schmitt-trigger inverter fabricated with silicon gate CMOS technology.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output.

The MC74VHC1G14 input structure provides protection when voltages up to 7.0 V are applied, regardless of the supply voltage. This allows the MC74VHC1G14 to be used to interface 5.0 V circuits to 3.0 V circuits.

The MC74VHC1G14 can be used to enhance noise immunity or to square up slowly changing waveforms.

- High Speed:  $t_{PD} = 4.0 \text{ ns}$  (Typ) at  $V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 1.0 \mu A$  (Max) at  $T_A = 25^{\circ}C$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Pin and Function Compatible with Other Standard Logic Families
- Chip Complexity: FETs = 101

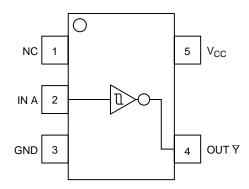


Figure 1. Pinout (Top View)

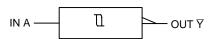


Figure 2. Logic Symbol



#### ON Semiconductor®

http://onsemi.com



SC70-5/SC-88A/SOT-353 DF SUFFIX CASE 419A



**MARKING** 



SOT23-5/TSOP-5/SC59-5 DT SUFFIX CASE 483



d = Date Code

| PIN ASSIGNMENT |                    |  |  |  |  |
|----------------|--------------------|--|--|--|--|
| 1              | NC                 |  |  |  |  |
| 2              | IN A               |  |  |  |  |
| 3              | GND                |  |  |  |  |
| 4              | OUT $\overline{Y}$ |  |  |  |  |
| 5              | V <sub>CC</sub>    |  |  |  |  |

#### **FUNCTION TABLE**

| A Input | ▼ Output |
|---------|----------|
| L       | Н        |
| Н       | L        |

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### **MAXIMUM RATINGS**

| Symbol                | ·                                      | Parameter  | Value                    | Unit |
|-----------------------|--|--|--------------------------|------|
| V <sub>CC</sub>       | DC Supply Voltage                      |  | -0.5 to +7.0             | V    |
| V <sub>IN</sub>       | DC Input Voltage                       |  | -0.5 to +7.0             | V    |
| V <sub>OUT</sub>      | DC Output Voltage                      |  | $-0.5$ to $V_{CC} + 0.5$ | V    |
| I <sub>IK</sub>       | DC Input Diode Current                 |  | -20                      | mA   |
| lok                   | DC Output Diode Current                |  | ±20                      | mA   |
| l <sub>OUT</sub>      | DC Output Sink Current                 |  | ± 12.5                   | mA   |
| I <sub>CC</sub>       | DC Supply Current per Supply Pin       |  | ±25                      | mA   |
| T <sub>STG</sub>      | Storage Temperature Range              |  | -65 to +150              | °C   |
| TL                    | Lead Temperature, 1 mm from Case       | e for 10 Seconds   | 260                      | °C   |
| TJ                    | Junction Temperature Under Bias        |  | + 150                    | °C   |
| $\theta_{JA}$         | Thermal Resistance                     | SC70-5/SC-88A (Note 1)<br>TSOP-5   | 350<br>230               | °C/W |
| P <sub>D</sub>        | Power Dissipation in Still Air at 85°C | SC70-5/SC-88A<br>TSOP-5  | 150<br>200               | mW   |
| MSL                   | Moisture Sensitivity                   |  | Level 1                  |      |
| F <sub>R</sub>        | Flammability Rating                    | Oxygen Index: 28 to 34   | UL 94 V-0 @ 0.125 in     |      |
| V <sub>ESD</sub>      | ESD Withstand Voltage                  | Human Body Model (Note 2)<br>Machine Model (Note 3)<br>Charged Device Model (Note 4) | > 2000<br>> 200<br>N/A   | V    |
| I <sub>LATCH-UP</sub> | Latch-Up Performance                   | Above V <sub>CC</sub> and Below GND at 125°C (Note 5)                                | ± 500                    | mA   |

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute—maximum—rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

- 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
- 2. Tested to EIA/JESD22-A114-A.
- 3. Tested to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA/JESD78.

#### RECOMMENDED OPERATING CONDITIONS

| Symbol                          | Parameter  | Min        | Max                  | Unit |
|---------------------------------|--|------------|----------------------|------|
| V <sub>CC</sub>                 | DC Supply Voltage  | 2.0        | 5.5                  | V    |
| V <sub>IN</sub>                 | DC Input Voltage   | 0.0        | 5.5                  | V    |
| V <sub>OUT</sub>                | DC Output Voltage  | 0.0        | V <sub>CC</sub>      | V    |
| T <sub>A</sub>                  | Operating Temperature Range  | -55        | +125                 | °C   |
| t <sub>r</sub> , t <sub>f</sub> | Input Rise and Fall Time $ \begin{array}{c} V_{CC} = 3.3 \ V \pm 0.3 \ V_{CC} = 5.0 \ V \pm 0.5 \ V_{CC} \end{array} $ | / –<br>/ – | No Limit<br>No Limit | ns/V |

## DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

| Junction<br>Temperature °C | Time, Hours | Time, Years |
|----------------------------|-------------|-------------|
| 80                         | 1,032,200   | 117.8       |
| 90                         | 419,300     | 47.9        |
| 100                        | 178,700     | 20.4        |
| 110                        | 79,600      | 9.4         |
| 120                        | 37,000      | 4.2         |
| 130                        | 17,800      | 2.0         |
| 140                        | 8,900       | 1.0         |

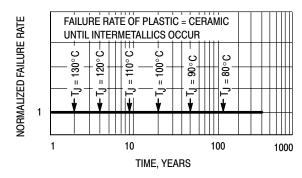


Figure 3. Failure Rate vs. Time Junction Temperature

#### DC ELECTRICAL CHARACTERISTICS

|                 |                                      |  | v <sub>cc</sub>   | T <sub>A</sub> = 25°C |                      |                      | T <sub>A</sub> ≤ 85°C |                      | -55 ≤ T <sub>A</sub> ≤ 125°C |                      |      |
|-----------------|--------------------------------------|--|-------------------|-----------------------|----------------------|----------------------|-----------------------|----------------------|------------------------------|----------------------|------|
| Symbol          | Parameter                            | Test Conditions                                    | (V)               | Min                   | Тур                  | Max                  | Min                   | Max                  | Min                          | Max                  | Unit |
| V <sub>T+</sub> | Positive Threshold<br>Voltage        |  | 3.0<br>4.5<br>5.5 | 1.85<br>2.86<br>3.50  | 2.0<br>3.0<br>3.6    | 2.20<br>3.15<br>3.85 |                       | 2.20<br>3.15<br>3.85 |                              | 2.20<br>3.15<br>3.85 | V    |
| V <sub>T-</sub> | Negative Threshold<br>Voltage        |  | 3.0<br>4.5<br>5.5 | 0.9<br>1.35<br>1.65   | 1.5<br>2.3<br>2.9    | 1.65<br>2.46<br>3.05 | 0.9<br>1.35<br>1.65   |                      | 0.9<br>1.35<br>1.65          |                      | V    |
| V <sub>H</sub>  | Hysteresis Voltage                   |  | 3.0<br>4.5<br>5.5 | 0.30<br>0.40<br>0.50  | 0.57<br>0.67<br>0.74 | 1.20<br>1.40<br>1.60 | 0.30<br>0.40<br>0.50  | 1.20<br>1.40<br>1.60 | 0.30<br>0.40<br>0.50         | 1.20<br>1.40<br>1.60 | V    |
| V <sub>OH</sub> | Minimum High-Level<br>Output Voltage | $V_{IN} \le V_T - Min$<br>$I_{OH} = -50 \mu A$     | 2.0<br>3.0<br>4.5 | 1.9<br>2.9<br>4.4     | 2.0<br>3.0<br>4.5    |                      | 1.9<br>2.9<br>4.4     |                      | 1.9<br>2.9<br>4.4            |                      | V    |
|                 |                                      | I <sub>OH</sub> = -4 mA<br>I <sub>OH</sub> = -8 mA | 3.0<br>4.5        | 2.58<br>3.94          |                      |                      | 2.48<br>3.80          |                      | 2.34<br>3.66                 |                      | V    |
| V <sub>OL</sub> | Maximum Low–Level<br>Output Voltage  | $V_{IN} \ge V_T + Max$ $I_{OL} = 50 \mu A$         | 2.0<br>3.0<br>4.5 |                       | 0.0<br>0.0<br>0.0    | 0.1<br>0.1<br>0.1    |                       | 0.1<br>0.1<br>0.1    |                              | 0.1<br>0.1<br>0.1    | V    |
|                 |                                      | I <sub>OL</sub> = 4 mA<br>I <sub>OL</sub> = 8 mA   | 3.0<br>4.5        |                       |                      | 0.36<br>0.36         |                       | 0.44<br>0.44         |                              | 0.52<br>0.52         | V    |
| I <sub>IN</sub> | Maximum Input<br>Leakage Current     | V <sub>IN</sub> = 5.5 V or GND                     | 0 to<br>5.5       |                       |                      | ±0.1                 |                       | ±1.0                 |                              | ±1.0                 | μΑ   |
| I <sub>CC</sub> | Maximum Quiescent<br>Supply Current  | $V_{IN} = V_{CC}$ or GND                           | 5.5               |                       |                      | 1.0                  |                       | 20                   |                              | 40                   | μΑ   |

#### AC ELECTRICAL CHARACTERISTICS Input $t_f = t_f = 3.0 \text{ ns}$

|  |                                   |                                  |  | T <sub>A</sub> = 25°C |            | <b>T</b> <sub>A</sub> ≤ 85° <b>C</b> |            | -55 ≤ T <sub>A</sub> ≤ 125°C |            |              |      |
|--|-----------------------------------|----------------------------------|--|-----------------------|------------|--------------------------------------|------------|------------------------------|------------|--------------|------|
| Symbol                                 | Parameter                         | Test Condit                      | tions  | Min                   | Тур        | Max                                  | Min        | Max                          | Min        | Max          | Unit |
| t <sub>PLH</sub> ,<br>t <sub>PHL</sub> | Maximum Propagation Delay, A to ₹ | $V_{CC} = 3.3 \pm 0.3 \text{ V}$ | $C_L = 15 \text{ pF}$<br>$C_L = 50 \text{ pF}$ |                       | 7.0<br>8.5 | 12.8<br>16.3                         | 1.0<br>1.0 | 15.0<br>18.5                 | 1.0<br>1.0 | 17.0<br>20.5 | ns   |
|  | A 10 1                            | $V_{CC} = 5.0 \pm 0.5 \text{ V}$ | $C_L = 15 pF$<br>$C_L = 50 pF$                 |                       | 4.0<br>5.5 | 8.6<br>10.6                          | 1.0<br>1.0 | 10.0<br>12.0                 | 1.0<br>1.0 | 11.5<br>13.5 |      |
| C <sub>IN</sub>                        | Maximum Input Capacitance         |                                  |  |                       | 5          | 10                                   |            | 10                           |            | 10           | pF   |

|                 |  | Typical @ 25°C, V <sub>CC</sub> = 5.0 V |    |
|-----------------|--|---|----|
| C <sub>PD</sub> | Power Dissipation Capacitance (Note 6) | 7.0                                     | pF |

<sup>6.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

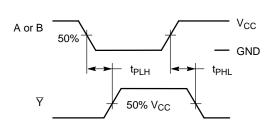
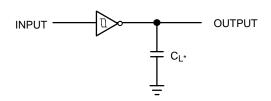


Figure 4. Switching Waveforms



\*Includes all probe and jig capacitance.
A 1–MHz square input wave is recommended for propagation delay tests.

Figure 5. Test Circuit

#### **DEVICE ORDERING INFORMATION**

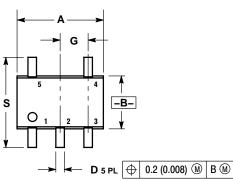
| Device Nomenclature    |                      |                             |            |                    |                   |                          |                           |                            |
|------------------------|----------------------|-----------------------------|------------|--------------------|-------------------|--------------------------|---------------------------|----------------------------|
| Device Order<br>Number | Circuit<br>Indicator | Temp<br>Range<br>Identifier | Technology | Device<br>Function | Package<br>Suffix | Tape &<br>Reel<br>Suffix | Package Type              | Tape and<br>Reel Size†     |
| MC74VHC1G14DFT1        | MC                   | 74                          | VHC1G      | 14                 | DF                | T1                       | SC70-5/SC-88A/<br>SOT-353 | 178 mm (7 in)<br>3000 Unit |
| MC74VHC1G14DFT2        | MC                   | 74                          | VHC1G      | 14                 | DF                | T2                       | SC70-5/SC-88A/<br>SOT-353 | 178 mm (7 in)<br>3000 Unit |
| MC74VHC1G14DTT1        | MC                   | 74                          | VHC1G      | 14                 | DT                | T1                       | SOT23-5/TSOP-5/<br>SC59-5 | 178 mm (7 in)<br>3000 Unit |

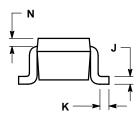
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **PACKAGE DIMENSIONS**

#### SC70-5/SC-88A/SOT-353 **DF SUFFIX**

5-LEAD PACKAGE CASE 419A-02 ISSUE G





- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

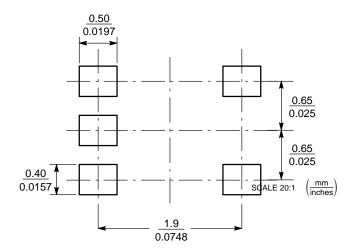
  2. CONTROLLING DIMENSION: INCH.

  3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.

  4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|     | INC       | HES   | MILLIN   | IETERS |  |  |  |
|-----|-----------|-------|----------|--------|--|--|--|
| DIM | MIN       | MAX   | MIN      | MAX    |  |  |  |
| Α   | 0.071     | 0.087 | 1.80     | 2.20   |  |  |  |
| В   | 0.045     | 0.053 | 1.15     | 1.35   |  |  |  |
| С   | 0.031     | 0.043 | 0.80     | 1.10   |  |  |  |
| D   | 0.004     | 0.012 | 0.10     | 0.30   |  |  |  |
| G   | 0.026     | BSC   | 0.65 BSC |        |  |  |  |
| Н   |           | 0.004 |          | 0.10   |  |  |  |
| J   | 0.004     | 0.010 | 0.10     | 0.25   |  |  |  |
| K   | 0.004     | 0.012 | 0.10     | 0.30   |  |  |  |
| N   | 0.008 REF |       | 0.20     | REF    |  |  |  |
| S   | 0.079     | 0.087 | 2.00     | 2.20   |  |  |  |

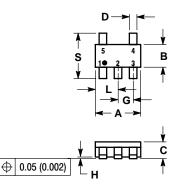
#### **SOLDERING FOOTPRINT**

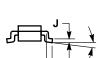


#### PACKAGE DIMENSIONS

#### SOT23-5/TSOP-5/SC59-5 **DT SUFFIX**

5-LEAD PACKAGE CASE 483-01 ISSUE C



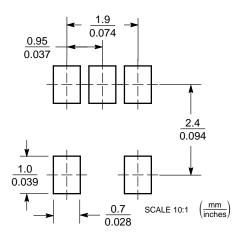


#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- ANSI 114-3M, 1902.
  CONTROLLING DIMENSION: MILLIMETER.
  MAXIMUM LEAD THICKNESS INCLUDES
  LEAD FINISH THICKNESS. MINIMUM LEAD
  THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- A AND B DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|     | MILLIN | IETERS | INC                 | HES    |
|-----|--------|--------|---------------------|--------|
| DIM | MIN    | MAX    | MIN                 | MAX    |
| Α   | 2.90   | 3.10   | 0.1142              | 0.1220 |
| В   | 1.30   | 1.70   | 0.0512              | 0.0669 |
| C   | 0.90   | 1.10   | 0.0354              | 0.0433 |
| D   | 0.25   | 0.50   | 0.0098              | 0.0197 |
| G   | 0.85   | 1.05   | 0.0335              | 0.0413 |
| Н   | 0.013  | 0.100  | 0.0005              | 0.0040 |
| ۲   | 0.10   | 0.26   | 0.0040              | 0.0102 |
| K   | 0.20   | 0.60   | 0.0079              | 0.0236 |
| L   | 1.25   | 1.55   | 0.0493              | 0.0610 |
| М   | 0      | 10     | 0                   | 10     |
| S   | 2.50   | 3.00   | $0.098\overline{5}$ | 0.1181 |

#### **SOLDERING FOOTPRINT**



ON Semiconductor and was are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its partnif rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.